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Size dependent carrier recombination in ZnO nanocrystals

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Experimental and theoretical studies of fluorescence decay were performed for colloidal ZnO nanocrystals. The fluorescence lifetime reduces from 22 ps to ~6 ps with decreasing nanocrystal radius. We postulate that non-radiative surface states dominate the carrier dynamics in small ZnO nanocrystals and perform Monte Carlo simulations incorporating carrier diffusion and carrier recombination to model the experimental fluorescence decay dynamics. The percentage of excitons undergoing nonradiative decay due to surface trapping is as high as 84% for nanocrystals with 8 nm radius, which explains the ultrafast decay dynamics observed in small ZnO nanostructures even at low temperatures. © 2010 American Institute of Physics. [doi:10.1063/1.3494535]

ZnO is one of the most attractive wide-band gap semiconductors for optoelectronic applications due to its huge exciton binding energy of 60 meV, which allows to design devices operating at temperatures exceeding 300 K. Reduction in physical size to nanoscale offers interesting applications for nanophotonics and nanovoltaics. Low-cost ZnO nanostructures have strong potential for fabrication of light-emitting diodes, nanolasers, nanosized sensors of high sensitivity and field emitters.1–3 Since nanocrystals (NCs) possess a relatively large surface with respect to their volume the influence of surface recombination might be significant for some important applications such as light emitters or solar-cells based on ZnO NCs. From this point of view it is necessary to understand in quantitative terms how the NC size affects the fluorescence properties of ZnO. In this paper, we report results of time-resolved fluorescence studies and model the dynamics using Monte Carlo simulations.

ZnO NCs are synthesized at 200 °C by a chemical precipitation method from the water solution of ZnCl2 (1:2) dropped slowly in the solution of NH4HCO3 mixed with dodecyl sodium sulfate of 8 nm for the as-grown NC. The grain radius of 45 nm is obtained after heating at 700 °C in air results in increase of the average grain radius to R = 45 nm. The average radius is estimated to 30 nm and 35 nm after annealing at 500 °C in forming gas [mixture of Ar and O2 (1:1)] and in air, respectively, [Figs. 1(d) and 1(e)]. The grain radius of 45 nm is obtained after heating at 700 °C in air [Fig. 1(f)]. We photoexcite the NCs nonresonantly using the third harmonics (λc=266 nm) from a Ti:sapphire 180 fs mode-locked laser with a repetition frequency of 75 MHz.

Figure 2(a) shows normalized fluorescence spectra (solid lines) and absorption spectra (dashed red lines) measured at T = 300 K for NCs with the average radius R of 8, 15, and 45 nm. The room temperature fluorescence and the absorption maxima for five different NC diameters are shown in Fig. 2(b) suggesting of exciton quantum confinement for NCs with radii up to 35 nm. We also observe an increasing Stock shift between the fluorescence and absorption maxima with decreasing NC size, reaching ~120 meV for NCs of R = 8 nm. The Stock shift size dependence was previously attributed to the additional confinement from surface traps.5 Figure 2(c) shows the fluorescence spectrum of the 45 nm ZnO NCs at different temperatures. At 5 K we observe that

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Figure 1. TEM images are shown for ZnO NCs with an average radius of 8 nm [(a) and (b)], 15 nm (c), 30 nm (d), 35 nm (e), and 45 nm (f). Image on (b) illustrates that nanoparticles have single crystal quality.
the spectrum is rather similar to bulk ZnO fluorescence with a dominating donor bound exciton (DBE) peak at ~3.36 eV and the first and second LO-phonon replicas of the free exciton at ~3.32 eV and 3.25 eV, respectively. The fluorescence spectra measured at higher temperatures demonstrate a broad emission band related to the free exciton transitions as bound excitons are expectedly quenched.

Characterization of the competition between exciton trapping at donor impurities and nonradiative exciton recombination for NCs of different sizes allows us to deduce the nature of the nonradiative channels in ZnO NCs. Figure 3(a) shows the fluorescence decay of 45 nm NCs for different temperatures. We observe a fastening of the fluorescence decay rate with increasing temperature, which is congruent with the thermal activation of nonradiative channels and the shorter lifetime of free excitons compared to donor bound excitons. Such temporal behavior of fluorescence for small NCs is different when compared to epitaxial or bulk ZnO, where lifetimes for both free and bound excitons change with increasing temperature. In colloidal NCs as the surface to volume aspect ratio increases with decreasing size the annihilation occurs predominantly at nonradiative surface states.

We use Monte Carlo for a quantitative analysis of carrier dynamics in ZnO NCs. The studied ZnO nanocrystals are considered as ideal spherical bodies of radius R. In the model, we assume that the initial population of excitons created under a short laser pulse in a sphere of radius R is N and excitons are distributed randomly within the spherical body. Excitons are assumed free particles at 300 K when all shallow traps are ionized. Furthermore, since R is larger than the exciton Bohr radius we can treat the exciton movement as a three-dimensional motion of a point particle having thermal velocity with the magnitude of 122 nm/ps obtained from

\[ v = \sqrt{3k_BT/m_{ex}} \]

where \( m_{ex} \) is an exciton mass in ZnO, calculated using the electron and the hole effective masses of 0.25\( m_0 \) and 0.66\( m_0 \) for the upper valence band, respectively. Excitons diffuse in a random trajectory within the sphere due to collisions with NCs the fluorescence decay rate remains virtually unaffected suggesting that in small nanocrystals nonradiative recombination of free excitons dominates over the formation of donor bound excitons. Such temporal behavior of fluorescence for small NCs is different when compared to epitaxial or bulk ZnO, where lifetimes for both free and bound excitons change (decrease) with increasing temperature. In colloidal NCs as the surface to volume aspect ratio increases with decreasing size the annihilation occurs predominantly at nonradiative surface states.

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imperfections or phonons and the probability of scattering processes is described by the electron momentum scattering time of $\sim 10^{-3}$ ps. We assume that excitons can undergo radiative or nonradiative annihilation depending on their position inside the NC. We consider two regions within the NC: (i) internal volume, where excitons recombine radiatively and (ii) “edge” area, in which excitons are getting bound to the surface states and can annihilate both radiatively and nonradiatively. The thickness of the “edge” spherical shell is taken to be 8 nm ($\sim 4a_B$, where $a_B \approx 2$ nm is the exciton Bohr radius). The probability of radiative decay is given by $k_r = 1/25$ ps$^{-1}$ corresponding to the bulk ZnO recombination rate measured at 300 K and the probability of nonradiative decay is described by the rate $k_{nr} = 1/8$ ps$^{-1}$ for all NCs, but the 8 nm radius, where we used $k_{nr} = 1/5$ ps$^{-1}$ optimized to fit the experimental fluorescence decay curves assuming a biexponential decay, as follows:

$$I(t) = \frac{N_i}{N}\exp(-k_rt) + \frac{N_e}{N}\exp[-(k_r + k_{nr})t],$$

where $N_i/N$ and $N_e/N$ are the calculated fraction of excitons annihilate inside the internal area and inside the “edge” region, respectively, using Monte Carlo simulation. Normalized experimental fluorescence decay curves (solid lines) together with Monte Carlo simulations (dashed lines) are shown in Fig. 4 for NCs of different size. All calculated curves are obtained using the same parameters except the NCs radius. Figure 4(f) shows the dependence of the percentage of excitons suffering nonradiative decay with the NCs size (circles). We found that $\sim 43\%$ of all excitons decay in the “edge” area and the percentage of excitons, which undergo nonradiative recombination is $\sim 31\%$ for the NC with the biggest radius of 45 nm. In the intermediate case, for the ZnO NC with $R = 15$ nm, the percentage of excitons undergoing nonradiative recombination is $\sim 69\%$. For the smallest NC with $R = 8$ nm, more than $84\%$ of all excitons annihilate nonradiatively at the surface area. The percentage of excitons decaying at the surface area of the NCs versus NC size is shown by rhombs in Fig. 4(f). Monte Carlo simulation performed for 5 K gives only negligible change ($\sim 1\%$) to the percentage of all excitons undergoing nonradiative recombination, which is consistent with a very short fluorescence decay time measured for these NCs at low temperature. The above model neglects the enhancement of the light-matter coupling strength and the retardation (exciton-polariton) effect with increasing NC size since these phenomena are predicted to be less important for small ZnO quantum dots.

In summary, we have observed that fluorescence lifetime reduces from 22 to $\sim 6$ ps with decreasing NC radius. The dominance of nonradiative surface recombination is confirmed by Monte Carlo simulations of the fluorescence decay. In NCs with $R = 8$ nm the calculated percentage of excitons recombining nonradiatively within the surface area exceeds 84%, which explains the unusually short fluorescence lifetime measured in such small ZnO NCs.

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